

Technical Data Data Sheet 4962, Rev.-

SILICON SCHOTTKY RECTIFIER DIE Low Forward Voltage Drop (175 °C T_J Operation)

Applications:

• Switching Power Supply • Converters • Free-Wheeling Diodes • Polarity Protection Diode

Features:

- Soft Reverse Recovery at Low and High Temperature
- Low Forward Voltage Drop
- Low Reverse Leakage Current
- Low Power Loss, High Efficiency
- High Surge Capacity
- Guard Ring for Enhanced Durability and Long Term Reliability
- Guaranteed Reverse Avalanche Characteristics
- Electrically / Mechanically Stable during and after Packaging

Maximum Ratings(1):

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V_{RWM}	-	100	V
Max. Average Forward	$I_{F(AV)}$	50% duty cycle, rectangular	7.5	Α
Current	, ,	wave form		
Max. Peak One Cycle Non-	I_{FSM}	8.3 ms, half Sine wave (1)	140	Α
Repetitive Surge Current				
Non-Repetitive Avalanche	E_AS	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 2.0 \text{A},$	13.0	mJ
Energy		L = 6.5 mH		
Repetitive Avalanche Current	I_{AR}	I _{AS} decay linearly to 0 in 1 μs	2.0	Α
		f limited by T_J max $V_A=1.5V_R$		
Max. Junction Temperature	T_J	-	-65 to +175	°C
Max. Storage Temperature	T_{stg}	-	-65 to +175	°C

Electrical Characteristics(1):

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop	V_{F1}	@ 7.5A, Pulse, T _J = 25 °C	0.84	V
	V_{F2}	@ 7.5A, Pulse, T _J = 125 °C	0.68	V
Max. Reverse Current	I _{R1}	@V _R = 100V, Pulse,	0.18	mA
		$T_J = 25 ^{\circ}C$		
	I _{R2}	@V _R = 100V, Pulse,	4.0	mA
		T _J = 125 °C		
Max. Junction Capacitance	C _T	$@V_R = 5V, T_C = 25 ^{\circ}C$	250	pF
		$f_{SIG} = 1MHz,$		
		$V_{SIG} = 50 \text{mV (p-p)}$		

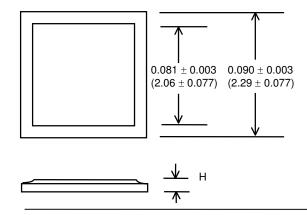
(1) in SHD package

^{• 221} West Industry Court ■ Deer Park, NY 11729-4681 ■ (631) 586-7600 FAX (631) 242-9798 •

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Mechanical Dimensions: In Inches / mm

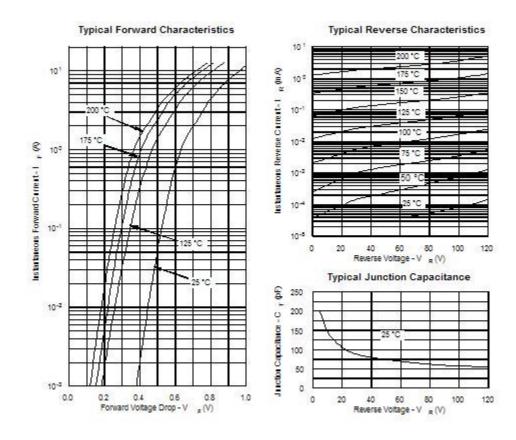


Bottom side metalization Ag - 30 kÅ minimum.

Top side metalization AI - 25 kÅ minimum or Ag - 30 kÅ minimum.

Bottom side is cathode, top side is anode.

Dimension H = 0.0105 \pm 0.001 (0.27 \pm 0.026) for Al top; Dimension H = 0.0155 \pm 0.001 (0.39 \pm 0.026) for Ag top.



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TECHNICAL DATA

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